**RECTIFIER DIODES** REVERSE VOLTAGE -50V TO 1000V FORWARD CURRENT -1A

# **DESCRIPTION**

The FM101W ~ FM107W are available in SOD-123FL package

## **FEATURES**

Available in SOD-123FL package

# ORDERING INFORMATION

Package Type	Part Number				
SOD-123FL	FM101W				
	FM102W				
	FM103W				
	FM104W FM105W				
					FM106W
		FM107W			
Note	SPQ: 3,000pcs/Reel				
AiT provides all RoHS Compliant Products					

# PIN DESCRIPTION



- 1. CATHODE
- 2. ANODE

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# ABSOLUTE MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at  $25^{\circ}$ C ambient temperature unless otherwise specified. Single phase half-wave 60 Hz , resistive or inductive load, for capacitive load current derate by 20 %.

Parameter		Symbol	FM 101W	FM 102W	FM 103W	FM 104W	FM 105W	FM 106W	FM 107W	Unit
Maximum Repetitive Peak Reverse Voltage		$V_{RRM}$	50	100	200	400	600	800	1000	V
Maximum RMS Volta	ge	V <sub>RMS</sub>	35	70	140	280	420	560	700	V
Maximum DC Blockir	ng Voltage	$V_{DC}$	50	100	200	400	600	800	1000	V
Maximum Average Forward  Rectified Current at T <sub>A</sub> =65°C		I <sub>F(AV)</sub>	1.0							А
Peak Forward Surge Current 8.3ms Single Half Sine Wave Superimposed on Rated Load (JEDEC Method)		lfsm	25							А
Maximum Instantaneous Forward Voltage at 1A		VF	1.3							V
Maximum DC Reverse Current at Rated DC Blocking Voltage	T <sub>A</sub> =25°C T <sub>A</sub> =100°C	l <sub>R</sub>	5 125					μΑ		
Maximum Reverse Recovery Time <sup>NOTE1</sup>		t <sub>rr</sub>	150 250 500				00	ns		
Typical Junction CapacitanceNOTE2		Сл	15							рF
Operating and Storage Temperature Range		TJ, TSTG	-55 ~150							°C

NOTE1: Measured with  $I_F$  = 0.5A,  $I_R$  = 1A,  $I_{rr}$ = 0.25A

NOTE2: Measured at 1MHz and applied reverse voltage of 4V D.C

RECTIFIER DIODES

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## TYPICAL CHARACTERISTICS

Figure. 1 Forward Current Derating Curve

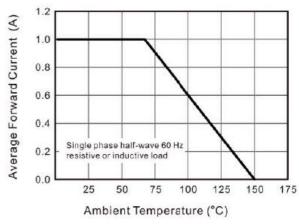


Figure. 3 Typical Instantaneous Forward

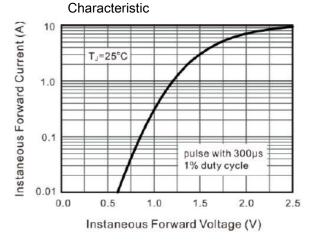


Figure. 5 Maximum Non-Repetitive Peak

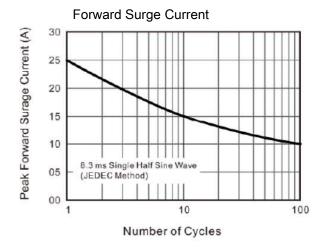


Figure. 2 Typical Reverse Characteristics

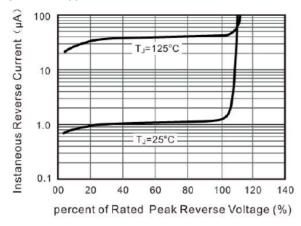
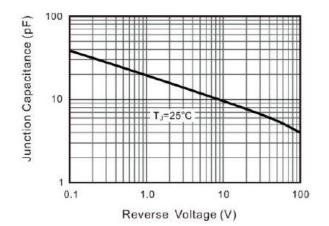


Figure. 4 Typical Junction Capacitance



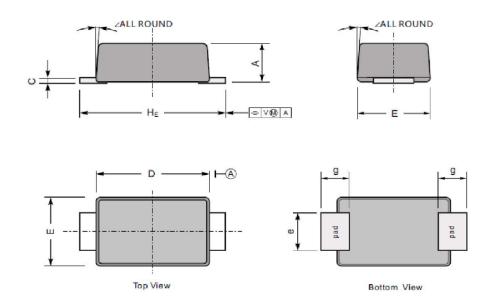
**RECTIFIER DIODES** 

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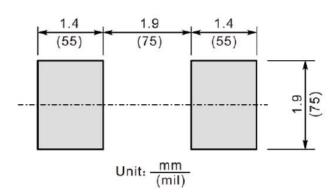
# **PACKAGE INFORMATION**

Dimension in SOD-123FL (Unit: mm)

Plastic surface mounted package; 2 leads



## The recommended mounting pad size



UN	NIT	Α	В	C	ш	е	g	HE	∠
mm	Max	1.1	0.20	2.9	1.9	1.1	0.9	3.8	
	Min	0.9	0.12	2.6	1.7	0.8	0.7	3.5	<b>7</b> °
mil	Max	43	7.9	114	75	43	35	150	,
	Min	35	4.7	102	67	31	28	138	

## FM101W ~FM107W



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